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16	43	587	6	Hits		79	4613	3265	83	8	Hits
((semiconductor and (electrode with (poly ad) silicon) (silicon) (silicon) (silicon) (silicon) (silicon) with (germanium ge))) and ((fatic line) and etching) rie)) and ((gate line) with (germanium))	(semiconductor and (electrode with ((poly adj silicon) (silicon) (si)) with (germanium ge))) and ((rapid adj ion and etching) rie)	semiconductor and (electrode with ((poly adj silicon) (silicon) (si)) with (germanium ge))	((semiconductor and ((electrode gate) with ((poly adj silicon) (silicon) (si)) and (germanium ge))) and (to adj (shape shaped))) and etch adj rate	Search Text	02/25/2002, EAST Version: 1.02.0008	(semiconductor and ((electrode gate) with ((poly adj silicon) (silicon) (si)) and (germanium ge))) and	semiconductor and ((electrode gate) with ((poly adj silicon) (silicon) (si)) and (germanium ge))	semiconductor and (electrode with ((poly adj	((((("438)/142") or ("438/154") or ("438/15") or ("438/16") or ("438/19") or ("438/19") or ("438/12") or ("438/14") or ("438/14") or ("438/14") or ("438/14") or ("438/14") or ("438/14") or ("438/15") or ("438/15"	((((("438/142") or ("438/15") or ("438/15") or ("438/16")	Search Text
USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	DBs	2.0008	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM	JPO; DERWENT; IBM 2002/02/23 15:02	JPO; DERWENT; IBM	USPAT	USPAT	DBs
2002/02/24 10:35	2002/02/24 10:34	2002/02/24 10:33	2002/02/23 15:03	Time Stamp		2002/02/23 15:03	2002/02/23 15:02	2002/02/24 10:33	2002/02/23 15:00	2002/02/23 14:40	Time Stamp

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	(semiconductor and ((electrode gate) with ((poly USPAT; US-PGPUB; E adj silicon) (silicon) (si)) and (germanium ge))) and JPO; DERWENT; IBM (t adj (shape shaped))	semiconductor and ((electrode gate) with ((poly adj USPAT, US-PGPUB; EPO; silicon) (si)) and (germanium ge))  JPO; DERWENT; IBM	semiconductor and (electrode with ((poly adj silicon) (silicon) (si)) and (germanium ge))	((((("438/142") or ("438/154") or ("438/157") or ("438/175") or ("438/175") or ("438/175") or ("438/175") or ("438/175") or ("438/187") or ("438/188") or ("	("438/454") or ("438/455") or ("438/458") or ("438/458") or ("438/4574") or ("438/574") or ("438/574") or ("438/574") or ("438/574") or ("438/575") or ("438/745") or ("438/745") or ("438/745") or ("438/745") or ("438/745") or ("438/745")). CCLS.) and (germanium ge)) and ((upper adj layer) (lower (ayer) (multilayer))) and etch adj rate
	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB		JPO; DERWENT; IBM 2002/02/24 10:33	USPAT	USPAT
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